

Dual P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
- 20	$0.019 \text{ at V}_{GS} = -10 \text{ V}$	- 8.4		
	0.031 at V _{GS} = - 4.5 V	- 6.7		

FEATURES

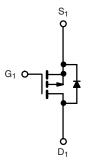
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_q Tested
- Compliant to RoHS Directive 2002/95/EC

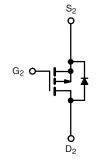
RoHS COMPLIANT HALOGEN

FREE

APPLICATIONS

- · Load Switching
 - Computer
 - Game Systems
- Battery Switching
 - 2-Cell Li-Ion





Ordering Information: Si4943BDY-T1-E3 (Lead (Pb)-free)

Top View

SO-8

Si4943BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)

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D₂
D₂

P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 20		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Dunin Courset /T 450 °C\d	T _A = 25 °C	I-	- 8.4	- 6.3	^
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	- 6.7	- 5.1	
Pulsed Drain Current		I _{DM}	- 30		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 1.7	- 0.9	
Mariana Barra Birainatian	T _A = 25 °C	D.	2.0	1.1	W
Maximum Power Dissipation ^a	T _A = 70 °C	- P _D	1.3	0.7	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R _{thJA}	46	62.5	
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	85	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	26	35	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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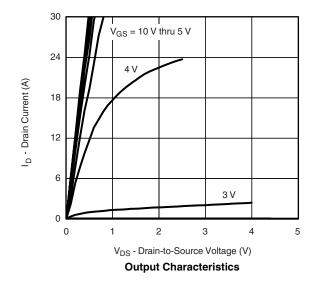
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Drain Current	1	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 5	μΑ	
On-State Drain Current ^a	n-State Drain Current ^a I _{D(on)} V _{DS} = - 5 V, V _{GS} = - 10 V		- 30			Α	
	D	V _{GS} = - 10 V, I _D = - 8.4 A		0.016	0.019	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 6.7 A		0.026	0.031		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 8.4 A		20		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.75	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			17	25		
Gate-Source Charge	Q _{gs}	V _{DS} = - 10 V, V _{GS} = - 5 V, I _D = - 8.4 A		5		nC	
Gate-Drain Charge	Q_{gd}			6.7			
Gate Resistance	R_g	f = 1 MHz	2.4	12	18	Ω	
Turn-On Delay Time	t _{d(on)}			11	17		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		10	15		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, $V_{GEN}=$ - 10 V, $R_g=6~\Omega$		94	140	ns	
Fall Time	t _f			60	90		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs		55	80		

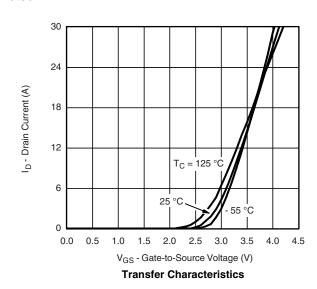
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



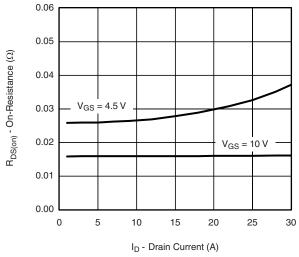




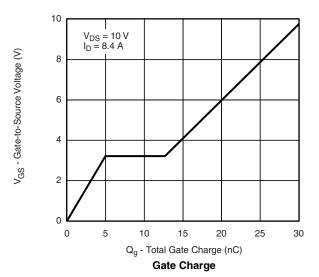


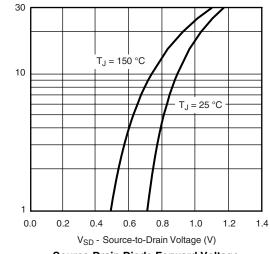


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

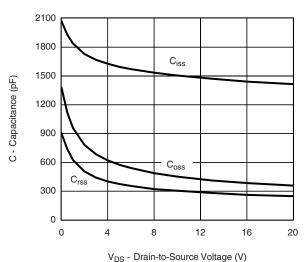


On-Resistance vs. Drain Current



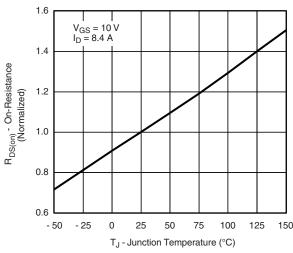


Source-Drain Diode Forward Voltage

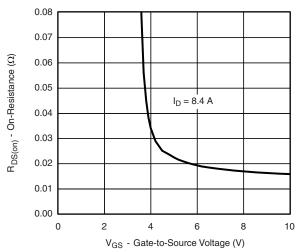


VDS - Diam-to-Source voltage (v)





On-Resistance vs. Junction Temperature



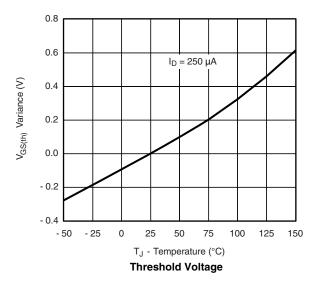
On-Resistance vs. Gate-to-Source Voltage

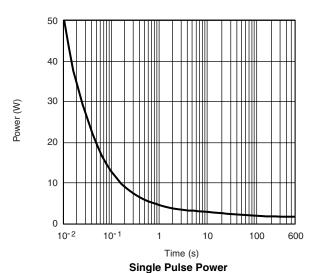
S - Source Current (A)

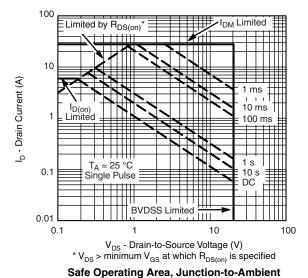
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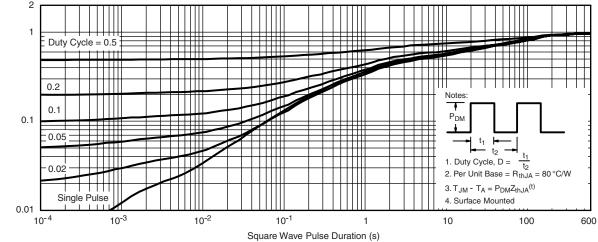
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted









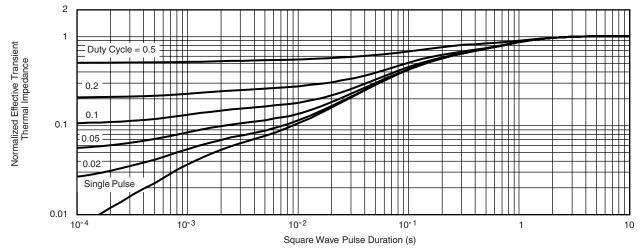


Normalized Thermal Transient Impedance, Junction-to-Ambient

Normalized Effective Transient Thermal Impedance



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg273073.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050	0.050 BSC		
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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